

# DuPont™ Kalrez® 6375UP

Optimal Seal Performance and Lower Cost of Ownership for Semiconductor Applications

Technical Information—Rev. 5, July 2010

To transform raw semiconducting materials into a useful device requires hundreds of chemical processing steps. A significant number of these steps involve aggressive acids, solvents, and bases (including amines) used to clean, rinse, etch or strip unwanted materials and contaminants from the wafer surface. These chemicals can attack elastomeric seals causing them to swell and degrade or to leach undesirable metallic and ionic extractables that affect integrated circuit functionality.

The trend toward larger wafers, smaller feature size, and decreasing thickness of deposited layers has placed increased emphasis on the need to minimize or eliminate sources of process contamination. Chemical and equipment manufacturers go to great lengths to minimize the potential for contamination that could result in chip defects.

DuPont has developed a number of products that resist chemical attack and are formulated and processed to minimize the potential for undesirable contaminants. The newest addition to our product line, **DuPont™ Kalrez® 6375UP**, has an excellent balance of performance characteristics required for semicon wet processing environments.

Process Type	Typical Chemicals*	Temp. Range, °C	DuPont™ Kalrez® 6375UP	DuPont™ Kalrez® 4079UP	DuPont™ Kalrez® 1050UP
Wafer Prep, Cleaning, and Rinsing	UPDI, Ozonated DI H <sub>2</sub> O TCE, IPA, Acetone Piranha, SC-1, SC-2 HF (49%), O <sub>3</sub>	25–125	Suggested Compound	Suitable Alternate	Consult DuPont s
Wet Etching	HNO <sub>3</sub> /HF/H <sub>2</sub> O H <sub>3</sub> PO <sub>4</sub> /HNO <sub>3</sub> /Acetic/H <sub>2</sub> O H <sub>3</sub> PO <sub>4</sub> /HNO <sub>3</sub> /HF/H <sub>2</sub> O, H <sub>3</sub> PO <sub>4</sub>	25–180	Suggested Compound	Suitable Alternate	Consult DuPont
Photolithography Developing, Stripping, Rinsing	H <sub>2</sub> SO <sub>4</sub> + Oxidant Organic Acids Chromic/Sulfuric Acid	25–125	Suggested Compound	Suitable Alternate	Consult DuPont
	NaOH, TMAH Xylene, Stoddard Solvent nMP	25–125	Suggested Compound	Suitable Alternate	Consult DuPont
	NMP/Alkanolamine DMSO/MEA DMAC/DEA Hydroxylamine	25–125	Suggested Compound	Consult DuPont	Suitable Alternate
Copper Plating	CuSO <sub>4</sub> Solution H <sub>2</sub> SO <sub>4</sub> , H <sub>2</sub> O <sub>2</sub> UPDI, Citric Acid	25–100	Suggested Compound	Suitable Alternate	Consult DuPont

\* Refer to the DuPont Chemical Resistance Guide for specific chemical and product compatibility in semiconductor applications.

Note: Product ratings are based on a combination of chemical resistance and extractable performance. In applications where extractables are not a critical concern, multiple products may be appropriate. For further assistance, contact DuPont and ask to speak with a Kalrez® Applications Engineer.



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## DuPont™ Kalrez® Offers Excellent Resistance to Chemical Attack

For many applications, low volume swell of elastomers is critical for proper equipment operation. Excessive swell may cause permanent seal failure due to equipment hang-up, extrusion, etc. While other physical property testing may be needed to adequately define product performance in a particular application, volume swell is an excellent indicator of resistance to chemical attack. The following data represents a summary of internal and external compatibility tests performed to determine the volume swell of products suggested for semiconductor wet process environments.

Immersion Chemistry	Exposure Conditions	Volume Swell		
		DuPont™ Kalrez® 6375UP	DuPont™ Kalrez® 4079UP	DuPont™ Kalrez® 1050UP
UPDI Water	85 °C, 30 days	0.7	2.3	5.5
Piranha	25 °C, 30 days	0.1	0.1	0.1
SC-1	25 °C, 30 days	0.6	1.1	0.6
SC-2	25 °C, 30 days	0.1	0.1	0.2
49% HF	25 °C, 30 days	2.8	0.6	1.8
Ammonium Hydroxide	100 °C, 7 days	2.6	9.8	Not Tested
Sulfuric Acid (H <sub>2</sub> SO <sub>4</sub> )	120 °C, 30 days	1.3	0.8	2.8
Nitric Acid (HNO <sub>3</sub> )	85 °C, 7 days	2.1	1.5	Not Tested
Phosphoric/Acetic/Nitric Acid	60 °C, 28 days	1.0	1.0	Not Tested
Hydrofluoric Acid/HNF <sub>4</sub>	60 °C, 28 days	0.0	1.0	Not Tested
Hydrochloric, Nitric Acid and H <sub>2</sub> O	60 °C, 28 days	5.0	6.0	Not Tested
n-Methylpyrrolidone	80 °C, 7 days	2.0	2.4	3.2
Dimethyl Acetamide	80 °C, 7 days	2.4	4.0	4.4
ACT 690C <sup>TM1</sup>	95 °C, 10 days	1.5	7.9	2.0
ACT-NP870 <sup>TM1</sup>	80 °C, 10 days	2.0	6.2	2.0
ACT 935 <sup>TM1</sup>	80 °C, 10 days	1.6	5.1	1.8
ACT NE-14 <sup>TM1</sup>	25 °C, 10 days	0.0	0.0	0.3
ACT CMI <sup>TM1</sup>	80 °C, 10 days	2.7	6.5	5.2
EKC265 <sup>TM2</sup>	75 °C, 7 days	1.0	2.8	0.7
EKC830 <sup>TM2</sup>	75 °C, 7 days	3.1	10.0	10.1
EKC4000 <sup>TM</sup> PCT <sup>2</sup>	75 °C, 7 days	0.7	1.7	2.5
PRS-1000 <sup>®3</sup>	95 °C, 10 days	1.5	7.9	2.0
PRS-3000 <sup>TM3</sup>	80 °C, 10 days	2.0	6.2	2.0
ALEG <sup>TM</sup> 310 <sup>3</sup>	80 °C, 10 days	1.6	5.1	1.8
REZI <sup>TM</sup> 28 <sup>3</sup>	80 °C, 10 days	2.7	6.5	5.2

\* Note: The volume swell values above should be used as an approximate indicator of relative compatibility performance. Generally <10% volume swell is desirable.

<sup>1</sup> Ashland, Inc.

<sup>2</sup> EKC Technologies, Inc.

<sup>3</sup> J.T. Baker (A Division of Mallinckrodt Baker, Inc.)

## Keep Contamination Under Control with Kalrez® Parts

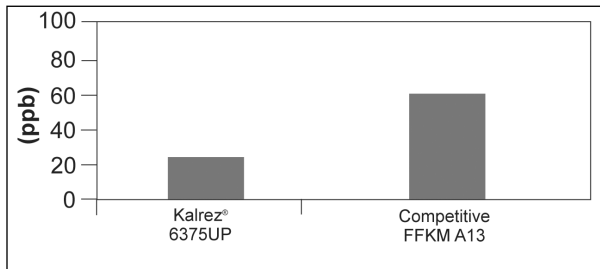
Semiconductor devices are vulnerable to many types of contaminants including trace chemicals (anions and total organic carbons—TOCs), metallic ions, and particles.

### Chemical Contamination (anions and TOCs)

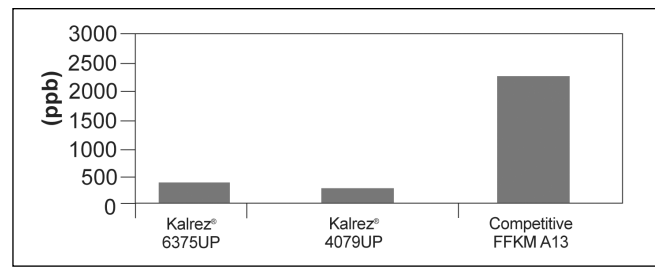
Two of the major sources of contamination in semiconductor processes are trace elements of unwanted chemicals (anions) and organic contaminants (TOCs). Process chemicals and process water can become contaminated and interfere with wafer processing. Chlorine (i.e., chloride ion) is such a contaminant and is rigorously controlled in process chemicals. In UPDI systems, TOCs can adhere to wafer surfaces and adversely affect oxide quality or film quality.

Elastomeric seals can be a source of this contamination. DuPont has developed products to minimize the potential for chemical and organic contamination.

**Chloride Ion Extractables After Immersion in UPDI Water for 1 Month at 85 °C\***



**Total Oxidizable Carbon After Immersion in UPDI Water for 1 Month at 85 °C\***

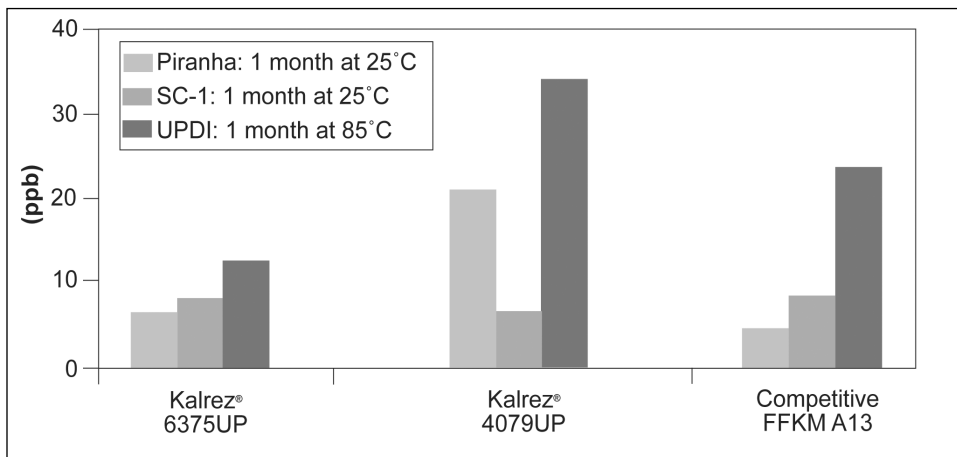


\*DuPont Extractables Test Procedure

**Metallic Ion Contamination**

Process chemicals can cause metallic ions to leach out of seal materials. These metallic ions, depending on type and quantity, can alter electrical properties and cause device failure to occur. Below is a summary of total metallic extractables after immersion of O-rings in various cleaning and wafer preparation process chemicals. DuPont™ Kalrez® 6375UP has an excellent balance of chemical resistance and low metallic extractables in a variety of process fluids.

**Total Metallic Extractables by ICP-MS\***



\* DuPont Extractables Test Procedure

**Typical Physical Properties<sup>1</sup>**

Kalrez® Product	Color	Hardness Shore A (pellet) <sup>2</sup>	Hardness Shore M (O-ring) <sup>3</sup>	Max. Cont. Service Temp, <sup>6</sup> °C	100% Modulus <sup>4</sup> MPa	Compression Set <sup>5</sup> at 70 hr 204°C, %
6375UP	Black	75	83	275	7.23	25
4079UP	Black	75	83	316	7.23	25
1050UP	Black	82	—	288	12.40	35

<sup>1</sup> Not to be used for specification purposes

<sup>2</sup> ASTM D2240 (pellet test specimens)

<sup>3</sup> ASTM D2240 and ASTM D1414 (AS568A K214 O-ring test specimens)

<sup>4</sup> ASTM D412 (dumbbell test specimens)

<sup>5</sup> ASTM D395 (pellet test specimens)

<sup>6</sup> DuPont proprietary test method

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